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# 60V, 2.5A Integrated Photo Flash Charger with IGBT Driver and Quench

# **DESCRIPTION**

The MP3352 is a fast, highly efficient, precision high-voltage photo-flash charger with integrated IGBT driver for xenon flash applications. The programmable peak current is up to 2.5A to ensure fast charging time. A  $200 \text{m}\Omega$  internal power switch minimizes the conduction loss. In addition, a 60V maximum voltage lowers the transformer turns ratio and improves the switching loss associated with the primary leakage inductance. External feedback provides 3% charge accuracy.

The MP3352 is available in a 16-pin 3mm x 3mm QFN package.

# **FEATURES**

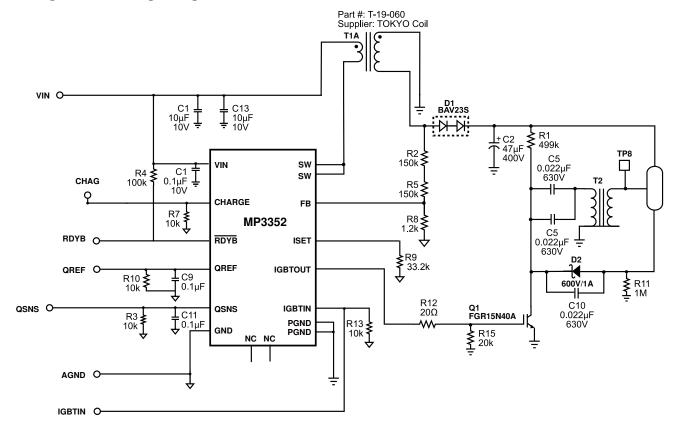
- Integrated 60V, 200mΩ Power Switch
- Programmable Peak Current Up to 2.5A
- 3% Charge Accuracy
- <1uA Shutdown Current</li>
- Integrated IGBT Driver
- Integrated Quench Feature

## **APPLICATIONS**

- Digital Still Cameras
- Optical Film Cameras
- Mobile Phones With Camera
- PDAs With Camera

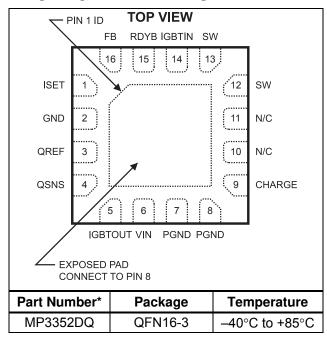
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## TYPICAL APPLICATION





# **PACKAGE REFERENCE**



For Tape & Reel, add suffix –Z (e.g. MP3352DQ–Z)
For RoHS compliant packaging, add suffix –LF (e.g. MP3352DQ–LF–Z)

# ABSOLUTE MAXIMUM RATINGS (1)

Thermal Resistance $^{(2)}$ $\theta_{JA}$ $\theta_{JC}$
Lead Temperature (Solder)+260°C
Junction Temperature+150°C
Storage Temperature55°C to +150°C
Operating Temperature Ranges: -40°C to +85°C
Maximum Operating Frequency400kHz
SW to GND0.3V to 60V
FB to GND0.3V to 6V
to GND0.3V to 6V
CHARGE, ISET, IGBTIN, RDYB, QREF, QSNS
V <sub>IN</sub> to GND0.3V to 6V

QFN16 (3mmx3mm)......50..... 12... °C/W

#### **Notes**

- 1) Exceeding these ratings may damage the device.
- 2) Measured on approximately 1" square of 1 oz copper.

# **ELECTRICAL CHARACTERISTICS**

 $(V_{IN}=V (CHARGE)=3.3V, TA = +25$ °C, unless otherwise noted.)

Parameter	Conditions	Min	Тур	Max	Unit	
Photoflash Capacitor Charger						
V <sub>IN</sub> Voltage Range		3		6	V	
V <sub>IN</sub> UVLO	Rising edge, hysteresis = 200mV	2.7	2.8	2.9	V	
V <sub>IN</sub> Quiescent Current	V(CHARGE)=High, V(SW) = 0, free run by $T_{ONMAX}$		1	2	mA	
V <sub>IN</sub> Quiescent Current	Charge Complete, V(CHARGE)=High, V(FB) = 1.3V		50		μΑ	
Shutdown Current from V <sub>IN</sub>	V(CHARGE)=Low			1	μΑ	
V <sub>SW</sub> Leakage Current	$V_{IN}$ =3.3V, $V_{SW}$ =60V, in Shutdown			2	μΑ	
SW ON resistance between SW and GND	Switch turn-on		0.2		Ω	
Charge Input High Voltage		2.4			V	
Charge Input Low Voltage				0.6	V	
Pull-down resistance of CHARGE pin	V(CHARGE)=3.3V		100K		Ω	
I <sub>PEAK1</sub>	$R_{SET}$ =33.2k $\Omega$	1.36	1.51	1.66	Α	
I <sub>PEAK2</sub>	$R_{SET}$ =100k $\Omega$	0.4	0.5	0.6	Α	
Charge completion detect voltage at FB		1.176	1.20	1.224	V	
FB input bias current I(FB)		-0.2		0.2	μΑ	
DCM Comparator threshold	With 1.2KΩ (1%) connected to FB	15	25	35	mV	



# **ELECTRICAL CHARACTERISTICS** (continued)

(V<sub>IN</sub>=V (CHARGE)=3.3V, TA = +25°C, unless otherwise noted.)

Parameter	Conditions	Min	Тур	Max	Unit
RDYB Leakage Current	V(RDYB)=3.3V			1	μΑ
RDYB Output Low Voltage	I <sub>SINK</sub> = 2mA		0.2		V
MAX T <sub>ON</sub>	Maximum T <sub>ON</sub> time	45	75	105	μs
Thermal Shutdown	Rising edge, hysteresis = 15°C		150		Ç
QREF input current	Q <sub>REF</sub> =0.2V to 1.2V	-0.1		0.1	μΑ
QSNS-QREF offset voltage	Q <sub>REF</sub> =0.2V to 1.2V	-50		50	mV
QSNS input current	Q <sub>REF</sub> =0.2V to 1.2V	-0.1		0.1	μΑ
QSNS to IGBT Delay	Q <sub>REF</sub> =0.2V to 1.2V		2		μs
IGBT Driver					
IGBTOUT pull-up ON			5		Ω
resistance			3		32
IGBTOUT pull-down ON			5		Ω
resistance			3		
IGBTIN Input High Voltage		2.4			V
IGBTIN Input Low Voltage				0.6	V
Propagation delay	IGBTIN rising/falling edge to		45		ns
	IGBTOUT rising/falling edge,				
	C <sub>GATE</sub> =6500pF				
IGBTOUT rise time	C <sub>GATE</sub> =6500pF,20% to 80%		60		ns
IGBTOUT fall time	C <sub>GATE</sub> =6500pF,20% to 80%		70		ns
Pull down resistance of IGBTIN			100K		Ω

# **PIN FUNCTIONS**

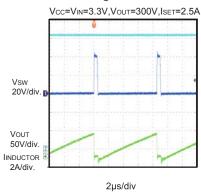
Pin #	Name	Function			
1	ISET	Peak Current Set Input. The peak current is 5 X 10 <sup>4</sup> the current flow out of this pin.			
2	GND	Analog Ground. Tie it directly to local ground plane.			
3	QREF	Quench reference input.			
4	QSNS	Quench sense input from light sensor.			
5	IGBTOUT	Output Drive for IGBT Gate. Connect this pin to the gate of the IGBT.			
6	VIN	Input Supply Pin. Connect it to system supply voltage. Bypass VIN to GND			
		with a 2x10µF or greater ceramic capacitor.			
7, 8	PGND	Power Ground. Ground connection for the power switch.			
9	CHARGE	Charge Enable Pin. A low-to-high transition on this pin puts the part into power			
		delivery mode. Once the target voltage is reached, the part will stop charging			
		the output. Toggle this pin will start charging again. Bring this pin low will			
		terminate the power delivery and put the part in shutdown.			
10, 11	N/C	No Connect			
12, 13	SW	Switch Pin. This is the drain of the internal power switch.			
14	IGBTIN	Logic Input Pin for IGBT Drive.			
15	RDYB	Open-Drain Power-Ready Output. RDYB goes low when the output voltage is			
		reached.			
16	FB	Feedback Pin. Trip voltage is 1.2V.			



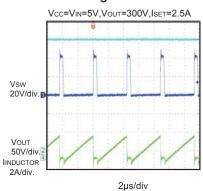
# TYPICAL PERFORMANCE CHARACTERISTICS

 $T_A = +25$ °C, unless otherwise noted.

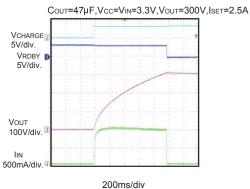
#### **Switching Waveform**



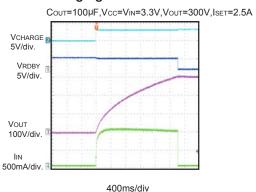
#### **Switching Waveform**



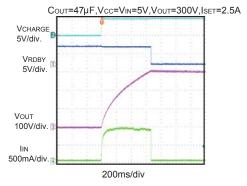
#### **Charging Waveform**



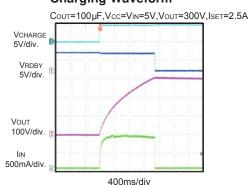
#### **Charging Waveform**



#### **Charging Waveform**



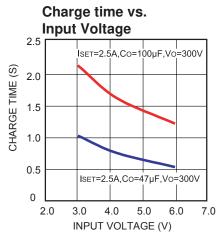
#### **Charging Waveform**

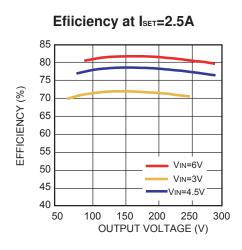


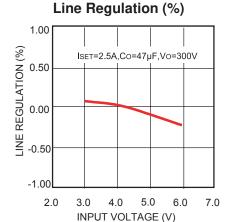


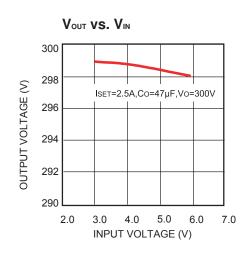
# TYPICAL PERFORMANCE CHARACTERISTICS (continued)

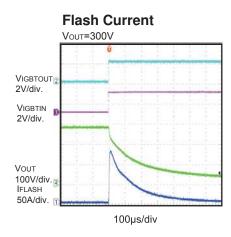
 $T_A = +25$ °C, unless otherwise noted.













# **TEST CIRCUITS**

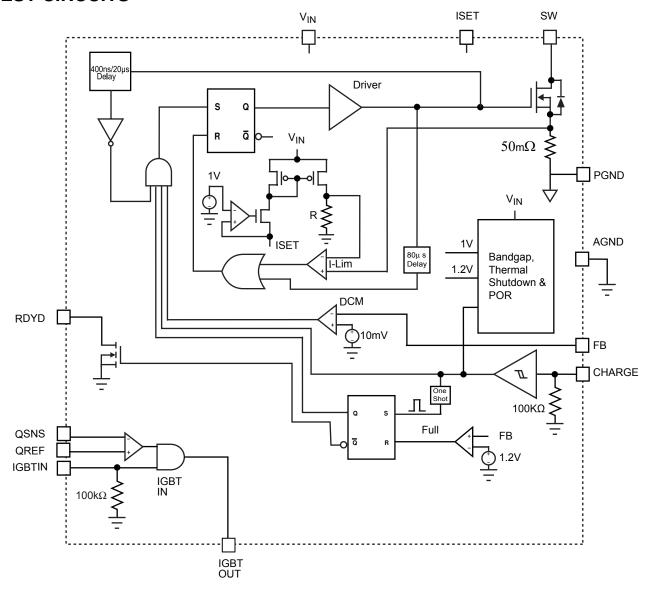


Figure 1—Functional Block Diagram



#### **APPLICATION INFORMATION**

MP3352 controlled flyback charger operates in critical conduction mode with peak current set by ISET pin. Output voltage is divided down through R1, R2 from the positive terminal of the transformer secondary and compares with 1.20V at FB pin. The low to high transition of CHARGE pin will enable the flyback converter to switch.

Charger may enter DCM mode when charge is close to full and actual OFF time is less than minimum Toff. Circuit will stop switching and RDYB will be pulled low once the flash capacitor is charged to 300V, a value set by R2, R5, and When the part is ready the internal R8. dissipation is reduced to just the circuits for IGBT driver. Toggle CHARGE pin will start charge again. Bringing CHARGE pin low terminates the power delivery and put the part in shutdown. A maximum T<sub>ON</sub> timer prevents pulling current from starved power source. If the ON time exceeds maximum Ton, the switch is forced OFF regardless of IPEAK detection. Integrated IGBT driver uses V<sub>IN</sub> as its power supply.

## **DCM Comparator**

DCM boundary is reached when V (FB) drops to zero. The DCM comparator compares V (FB) and a fixed offset voltage of 25mV to account for the comparator delay.

#### **Charge Speed**

The output capacitor charging speed is determined by:

$$T_{charge} \propto \frac{I_{LIM}}{\frac{1}{V_{IN}} + \frac{N}{V_{OUT}}}$$

#### **Setting Peak Charge Current**

MP3352's peak charge current ( $I_{SET}$ ) can be set by an external resistor,  $R_{SET}$  from the ISET pin to ground. The value of  $R_{SET}$  can be calculated from:

$$R_{SET}(K\Omega) = \frac{50}{I_{SET}(A)}$$

For example, for 2.5A peak charge current,  $R_{\text{SET}}$  is  $20k\Omega$ .

#### **Primary Inductance**

The primary inductance is calculated based on the minimum off time period:

$$L_{primary} \ge \frac{V_{out}T_{min,off}}{NI_{peak}}$$

V<sub>OUT</sub>: output voltage about 300V T<sub>MIN-OFF</sub> Minimum off time 300ns. I<sub>PEAK</sub>: primary peak current

#### **Turns Ratio**

The minimum turns ratio of the flyback transformer is obtained as:

$$N \ge \frac{V_{out}}{V_{ds} - V_{in}}$$

V<sub>DS</sub>: FET drain-source voltage V<sub>IN</sub>: Input voltage 3~5V

Table 1—	-Recommend	led Trans	former	Table

Part Number	Description	Size (L×W×H)	Vendor	
TTRN-038S	1:8, Lprimary = $6\mu$ H, for $I_{LIM}$ = 2.5	6.4mm×7.7mm×4.0mm	TOKYO Coil	
T-19-060	Amax	0.4111111^7.7111111^4.0111111	TOKTO COII	
750310448	1:8, Lprimary = $6\mu$ H, for $I_{LIM}$ = 2.5	7mm×10mm×5mm	Wurth	
750510440	Amax	7111112 10111112511111	Electronics	
LDT565630T-042	1:8, Lprimary = $6\mu$ H, for $I_{LIM}$ = $2A$	5.8mm×5.8mm×3mm	TDK	
LD13030301-042	only	5.611111^5.6111111^5111111	IDN	



#### **Setting Output Voltage**

The output voltage is set by selecting the resistive voltage divider ratio. If we use  $1.2k\Omega$  the low side resistor (R8) of the voltage divider, we can determine the high side resistor (R2, R5) by the equation:

$$R_2 = R_5 = \frac{1}{2} \frac{V_{out} - V_{FB}}{V_{FB}} R_8$$

#### **Output Diode Selection**

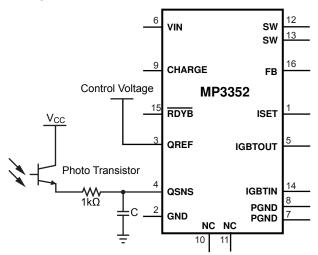
The reverse voltage of the output diode is determined by:

$$V_{\scriptscriptstyle D} = V_{\scriptscriptstyle out} + NV_{\scriptscriptstyle in}$$

#### **Quench Function**

MP3352 has build-in quench function to accurately control exposure time and preserve power, thus to extend battery life.

When output capacitor is fully charged and IGBTIN (pin14) is set high, internal IGBT driver drives the gate of IGBT high and fires the flash strobe. Once the photo transistor gets the flash light, it starts to charge C and the voltage of C represents the total exposure. IGBT will be off when the voltage on C exceeds the control voltage on QREF (Pin3)



#### TYPICAL APPLICATION CIRCUIT

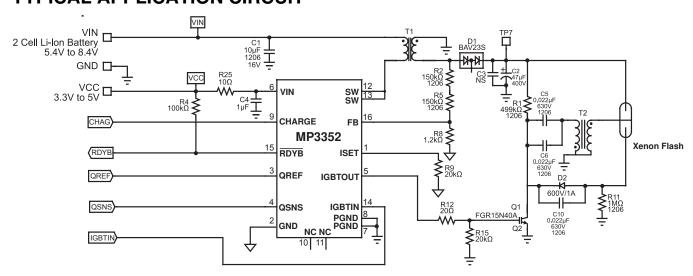
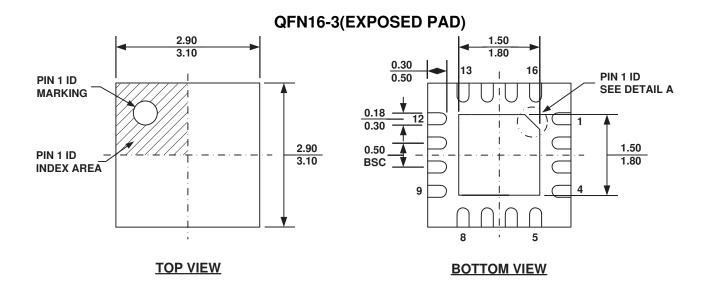
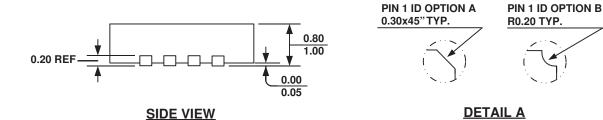


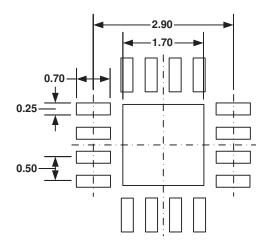
Figure 2—Application Circuit for 2 Cell Li-Ion Battery Photo Flash Charger



## **PACKAGE INFORMATION**







#### **NOTE:**

- 1) ALL DIMENSIONS ARE IN MILLIMETERS.
- 2) EXPOSED PADDLE SIZE DOES NOT INCLUDE MOLD FLASH.
- 3) LEAD COPLANARITY SHALL BE 0.10 MILLIMETER MAX.
- 4) DRAWING CONFORMS TO JEDEC MO-220, VARIATION VEED-4.
- 5) DRAWING IS NOT TO SCALE.

#### RECOMMENDED LAND PATTERN

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